

S-UM5588

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OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER

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Rev.1.0 00

S-UM5588 is a Octal programmable 5-level high-voltage ultrasound transmit beam-former. The S-UM5588 comprises control logic, waveform memory, delay calculator, level translators, gate drive buffers with floating voltage regulators, high-voltage, high-current MOSFETs, and active T/R switches.

Functions

• Octal programmable 5-level transmit beam-former with active T/R-switch

Features

- 0 to ±100V output voltage
- ±2A source and sink current for the 1st and 2nd high-voltage pulses (VPP1/VNN1, VPP2/VNN2)
- 2-mode output current control for the 2nd high-voltage rail
- ±1A source and sink peak current for active ground clamp
- 250Ω active ground clamp without blocking diode for anti-leakage
- 20MHz output frequency at ±60V output, 220pF load
- Symmetrical positive and negative pulse waveforms for low 2nd order harmonic distortion
- 1.8V to 3.3V LVCMOS logic interface
- Waveform memory and registers with 100MHz Write / 50MHz Read SPI
- 0.2µs to 41µs common delay time range from TRIG signal
- 0 to 1.275µs channel-to-channel delay time range
- 5ns channel-to-channel delay time resolution with dual-edge 100MHz LVDS/LVCMOS clock
- Minimum 10ns pulse width with 5ns time resolution with dual-edge 100MHz LVDS/LVCMOS clock
- 15Ω active T/R switch
- Noise-cut diodes at each high-voltage output
- High-voltage clamp diodes between each high-voltage output and power rails
- Automatic thermal protection with indicator
- Power-up/down reset function for free power sequencing and for fail-safe in abrupt power drop
- Latch-up free, low crosstalk between channels by SOI CMOS technology
- QFN-68(1010)B: 68-lead 10×10mm QFN package (RoHS compliant)

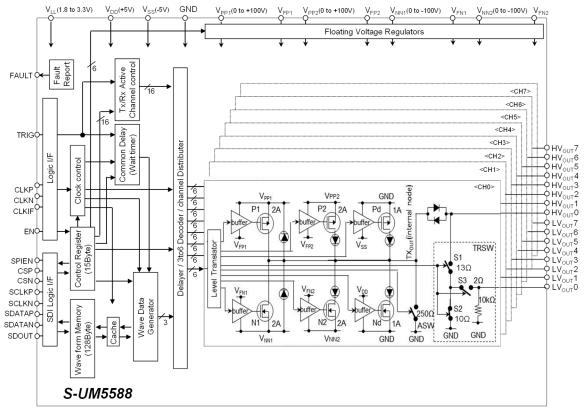


Figure 1 Block Diagram

■ Absolute Maximum Ratings

T_A=25°C unless otherwise specified.

No.	Items	Symbol	Value	Units	Condition
1	Logic supply voltage	VLL	-0.4 to +7	V	
2	Positive supply voltage	Vdd	-0.4 to +7	V	
3	Negative supply voltage	Vss	-7 to +0.4	V	
4	Positive high-voltage supplies	Vpp1, Vpp2	-0.5 to +105	V	
5	Negative high-voltage supplies	Vnn1,Vnn2	-105 to +0.5	V	
6	High-voltage outputs (x=0 to 7)	HVoutx	-105 to +105	V	
7	Low-voltage outputs (x=0 to 7)	LVoutx	-1 to +1	V	
8	Logic output voltage	SDOUT, FAULT	-0.4 to +7	V	
9	Logic input voltages	EN, CLKIF, CLKP, CLKN, TRIG, SPIEN, CSP, CSN, SCLKP, SCLKN, SDATAP, SDATAN	-0.4 to +7	V	
10	Operating junction temperature	TJop	-20 to +125	°C	
11	Storage temperature	Tstg	-55 to +150	°C	
12	Maximum power dissipation	P _{Dmax}	4	W	

Table 1 Absolute Maximum Ratings

Remark Stresses beyond the absolute maximum ratings may cause permanent damage to the product.

Operating Supply Voltages and Logic Inputs

1. Operating supply voltage and temperature

Table 2	Operating Supply Voltage and Temperature
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No.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	Logic supply voltage	VLL	1.71	1.8 to 3.3	3.6	V	
2	Positive supply voltage	V _{DD}	4.75	5	5.25	V	
3	Negative supply voltage	Vss	-5.25	-5	-4.75	V	
4	Positive high-voltage supplies	Vpp1, Vpp2	0	-	100	V	
5	Negative high-voltage supplies	V _{NN1} , V _{NN2}	-100	-	0	V	
6	IC substrate voltage *1	V _{SUB}	_	0	-	V	
7	V _{PP_} , V _{NN} _ slew rate	SRMAX	_	_	25	V/ms	
8	Operating free-air Temperature	Ta	0	_	75	°C	

*1. The package exposed pad internally connected to the chip substrate must be soldered to the ground.

2. Logic inputs and outputs

2.1 LVDS differential logic inputs

				-			2 IV:
No.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	High-level input voltage	VIH	1.265	-	-	V	VIHCMR(Typ)+VDIFF(Min)/2
2	Low-level input voltage	VIL	-	-	1.135	V	Vінсмк(Typ)-Vdiff(Min)/2
3	Differential input voltage range	VDIFF(range)	0.13	0.35	0.49	±V	Same as voltage swing
4	Differential input voltage peak to peak swing	VDIFF(p-p)	0.26	0.7	0.98	V _{pp}	Differential peak-to-peak absolute voltage swing
5	Input voltage common mode range	VIHCMR	0.84	1.2	1.56	V	
6	High-level input current	Іін	_	-	5.8	mA	
7	Low-level input current	١L	_	-	5.8	mA	
8	Input rise/fall time	tr, tr	_	-	600	ps	20% to 80% of VDIFF
	Input clock frequency (Tx)	fclк	_	-	100	MHz	CLKP/CLKN, SCLKP/SCLKN
9		2	_	-	100	MHz	SCLKP/SCLKN (Write mode)
	Input clock frequency (SPI)	fsclk	_	-	50	MHz	SCLKP/SCLKN (Read mode)
10		Dclk	48	50	52	%	CLKP/CLKN
10	Clock duty cycle	DSCLK	45	50	55	%	SCLKP/SCLKN
11	CS setup time	tsu_cs	2.5	-	_	ns	CS to SCLK rise
12	CS hold time	t _{HLD_CS}	2.5	-	_	ns	CS to SCLK rise
			1043Tsclk	_	_	ns	Data write to memory
			1050Tsclk	_	_	ns	Data read from memory
			75Tsclk	_	_	ns	Data Write to 7Byte register
13	CS width	tw_cs	82Tsclk	-	_	ns	Data read from 7Byte register
			147Tsclk	_	_	ns	Data write to 16Byte register
			154Tsclк	_	_	ns	Data read from 16Byte register
			26Tsclk	_	_	ns	Data read of other register
14	SDATA setup time	tsu_sdata	2.5	_	_	ns	SDATA to SCLK rise
15	SDATA hold time	thld_sdata	2.5	_	_	ns	SDATA to SCLK rise

Table 3 CLKP/CLKN, CSP/CSN, SCLKP/SCLKN, SDATAP/SDATAN

Remark External termination Resister (100Ω) is necessary for LVDS I/F differential inputs.

2.2 CMOS logic inputs & outputs

Table 4CLKP/CLKN, CSP/CSN, SCLKP/SCLKN, SDATAP/SDATAN*3EN, CLKIF, TRIG, SPIEN, SDOUT

No.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	High-level logic input voltage	VIH	$0.8V_{LL}$	1	VLL	V	
2	Low-level logic input voltage	VIL	0	1	0.2VLL	V	
3	Logic input capacitance	CIN	_	3	_	pF	
4	Logic input high current ^{*1}	Іін	-10	-	10	μA	
5	Logic input low current *2	lı∟	-10	-	10	μA	
6	Input rise/fall time	tr,t _f	1	I	2.0	ns	10% to 90% of signal
7		4	1.5	I	_		LVDS clock
7	TRIG fall to clock rise setup time	ISU_IRFtoCKR	1.5	I	_	ns	CMOS clock
	TRIG fall to clock rise hold time	thld_trftoCKR	1.5	I	_		LVDS clock
8			1.5	I	_	ns	CMOS clock
9	TRIG width	tw_trig	3T _{CLK}	_	_	ns	
10	High-level logic output voltage	Vон	$0.8V_{LL}$	_	VLL	V	SDOUT
11	Low-level logic output voltage	Vol	0	_	$0.2V_{LL}$	V	SDOUT
12	Logic output off leak current	IOFFLEAK	-10	-	10	μA	SDOUT Hi-Z output
			8	12	18	ns	V _{LL} =1.8V, 10pF load
13	SDOUT propagation delay	td_sdout	7	11	17	ns	V _{LL} =2.5V, 10pF load
			6	10	16	ns	V _{LL} =3.3V, 10pF load

*1. CLKIF has 50µA leakage at V_{LL}=2.5V due to 50k Ω internal pull-down resistor.

*2. EN, SPIEN has 50µA leakage at V_{LL}=2.5V due to 50k Ω internal pull-up resistor.

*3. Differential CMOS or Single-ended CMOS is also available for CLKP/N, CSP/N, SCLKP/N and SDATAP/N. In case of single-ended CMOS, N-terminals (CLKN, CSPN, SCLKN and SDATAN) need to be connected to half of V_{LL} (V_{LL}/2).

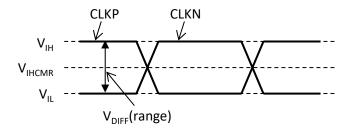
2.3 Open drain output

Table 5 FAULT

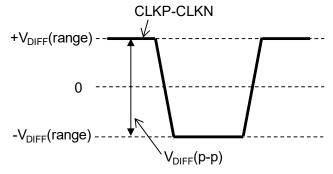
No.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	Pull-up voltage	Vpufault	1	1	VLL	V	Connected to V_{LL} with R1
2	Output low voltage	Volfault	1	1	0.5	V	Active, V _{LL} =2.5V, R1=2.5kΩ
3	Output current	IFAULT	-	1.0	_	mA	V _{LL} =2.5V, R1=2.5kΩ
4	Off leak current	IOFFLEAK	-10	-	10	μA	Disabled (Hi-Z)

2.4 Logic inputs timing chart

2.4.1 LVDS clock inputs









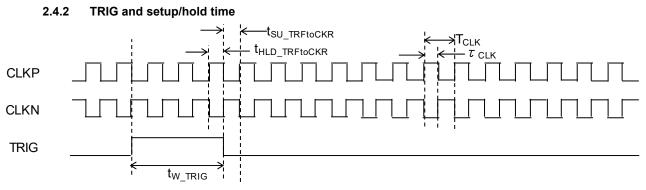
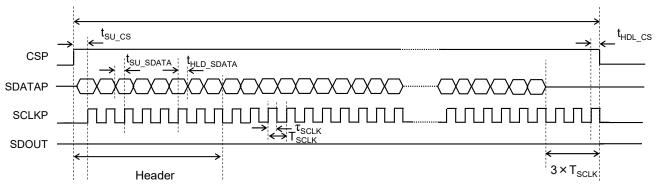
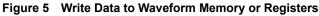


Figure 4

2.4.3 SPI inputs and setup/hold time





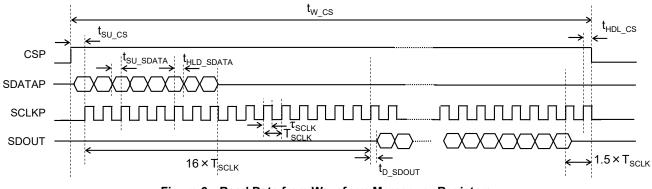
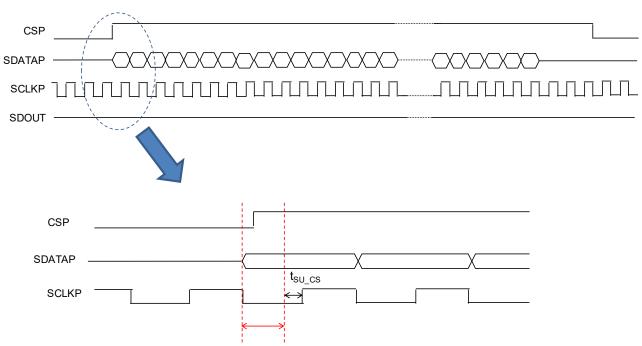
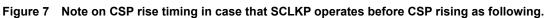


Figure 6 Read Data from Waveform Memory or Registers



2.4.4 Note on CSP rise timing



In case that SCLKP operates before CSP rising, CSP has to rise during SCLKP is "low" except for setup time "tsu_cs".

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Typical Application Circuit

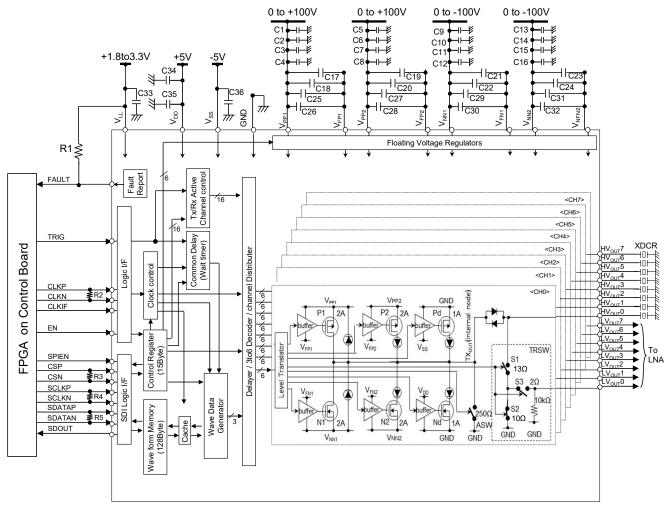


Figure 8 Typical Application Circuit

RemarkC1 to C16: Ceramic capacitors of $\geq 200V 0.1\mu$ F to 1μ F
C17 to C24: Ceramic capacitors of $\geq 16V 10\mu$ F
C25 to C36: Ceramic capacitors of $\geq 16V 0.1\mu$ F
R1: 2.5k Ω
R2 to R5: 100Ω (for LVDS)

Note:

- 1. High-voltage power supply pins, VPP/VNN, can draw fast transient currents up to ±2.0A. Therefore, ceramic capacitors of ≥200V 0.1µF to 1µF (C1 to 16) should be connected as close to the pins as possible for bypassing purpose.
- 2. Ceramic capacitors of ≥16V 10µF (C17 to 24), and ≥16V 0.1µF (C25 to 36) should also be connected between high-voltage power supply pins and corresponding floating voltage pins VFP/VFN, and low-voltage power supply pins for bypassing purpose. Connect those as close to the pins as possible.
- 3. It is also important to minimize the trace length and to have enough trace width of those high voltage and floating voltage lines.
- 4. The thermal tab on the bottom of the package must be soldered to the GND.
- 5. External 100 Ω should be connected between differential LVDS inputs of SPI and Clock.

Electrical Characteristics

1. Operating supply currents

Table 6 Operating Supply Currents (1/2)

 $V_{LL}=2.5V, V_{DD}/V_{SS}=\pm 5V, T_{A}=25^{\circ}C, CLKP/CLKN=100MHz, HV_{OUT} \ load=220pF//200\Omega, LV_{OUT} \ load=47pF//200\Omega, unless otherwise specified.$

					Spec			
No.		Items	Symbol	Min.	Тур.	Max.	Units	Conditions
		SPIEN=H		_	0.05	_	mA	
1	VLL current	SPIEN=L	Illqd	-	0.1	-	mA	
_	N/	SPIEN=H		-	5.5	-	mA	Quiescent current-1
2	VDD current	SPIEN=L	IDDQD	-	13.5	-	mA	EN=1(Disable)
3	Vss current		Issqd	_	1	-	mA	Current mode 1 (CC='1')
4	V _{PP1} current		IPP1QD	_	0.1	-	mA	Vpp1/Vnn1=±100V
5	VPP2 current		IPP2QD	_	0.1	-	mA	Vpp2/Vnn2=±100V
6	V _{NN1} current		I _{NN1QD}	_	0.1	1	mA	
7	V _{NN2} current		I _{NN2QD}	_	0.1	-	mA	
		SPIEN=H		_	0.1	I	mA	
8	V _{LL} current	SPIEN=L	ILLQE	_	0.15	I	mA	
		SPIEN=H,			12		mA	
		CLKIF=H(CMOS)		—	12	_	mA	
		SPIEN=H,			14	_	mA	
9	V _{DD} current	CLKIF=L(LVDS)		_	14	_	ША	Quiescent current-2
9		SPIEN=L,	IDDQE	_	20	_	mA	EN=0(Enable)
		CLKIF=H(CMOS)		_	20	_	ША	Current mode 1 (CC='1')
		SPIEN=L,		_	22	_	mA	Vpp1/Vnn1=±100V
		CLKIF=L(LVDS)			~~~		110/	Vpp2/Vnn2=±100V
10	Vss current		ISSQE	-	1	-	mA	-
11	V _{PP1} current		IPP1QE	-	0.3	-	mA	-
12	V _{PP2} current		IPP2QE	-	0.3	-	mA	-
13	V _{NN1} current		I _{NN1QE}	-	0.3	-	mA	-
14	V _{NN2} current	1	I _{NN2QE}	-	0.3	-	mA	
15	V _{LL} current	SPIEN=H	ILLPW	-	0.1	_	mA	-
		SPIEN=L		-	0.15	-	mA	-
		SPIEN=H,		_	15	_	mA	
		CLKIF=H(CMOS)						PW operating current
		SPIEN=H,		_	17	_	mA	EN=0
16	V _{DD} current	CLKIF=L(LVDS)	IDDPW					Current mode 1 (CC='1')
		SPIEN=L,		_	23	_	mA	8-channel active
		CLKIF=H(CMOS)						Bipolar 3-level 2-cycle
		SPIEN=L,		_	25	_	mA	f=5MHz, PRT=200µs
47)/ 	CLKIF=L(LVDS)						VPP1/VNN1=±60V
17	Vss current		ISSPW	_	2	-	mA	Vpp2/Vnn2=±5V
18			PP1PW	_	4	_	mA	4
19	VPP2 current		PP2PW	_	0.3	_	mA	4
20	V _{NN1} current		INN1PW	_	4	_	mA	4
21	V _{NN2} current		NN2PW	—	0.3	—	mA	<u> </u>

OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER Rev.1.0 00 S-UM5588

Table 6 Operating Supply Currents (2/2)

VLL=2.5V, VDD/VSS=±5V, TA=25°C, CLKP/CLKN=100MHz, HVout load=220pF//200Ω, LVout load=47pF//200Ω unless otherwise specified.

No.		Items	Symbol		Spec	-	Units	Conditions
INO.		nems	Symbol	Min.	Тур.	Max.	Units	Conditions
16	V⊥∟ current	SPIEN=H		-	0.1	_	mA	
10	VLL current	SPIEN=L	ILLCW1	-	0.15	_	mA	
		SPIEN=H,			108			
		CLKIF=H(CMOS)		-	100	_	mA	
		SPIEN=H,			110			CW operating current-1
17	Voo current	CLKIF=L(LVDS)	I	_	110	-	mA	EN=0, CKDIV[1:0]=10
17	VDD current	SPIEN=L,	DDCW1	_	116		mA	Current mode 1 (CC='1') 8-channel active
		CLKIF=H(CMOS)		_	110	-	ma	
		SPIEN=L,			118	_	mA	Bipolar 3-level Continuous f=5MHz
		CLKIF=L(LVDS)		-	110	_	mA	$V_{PP1}/V_{NN1}=\pm60V$
18	Vss current		Isscw1	_	24	-	mA	$V_{PP2}/V_{NN2}=\pm5V$
19	VPP1 current		IPP1CW1	-	0.3	_	mA	V PP2/ V NN2-10 V
20	VPP2 current		IPP2CW1	-	190	_	mA	
21	V _{NN1} current		IPP2CW1	_	0.3	_	mA	
22	V _{NN2} current		INN2CW1	1	200	_	mA	
22		SPIEN=H		1	0.1	_	mA	
23	V _{LL} current	SPIEN=L	ILLCW2	1	0.15	_	mA	
		SPIEN=H,			105			
		CLKIF=H(CMOS)		-	105	-	mA	
		SPIEN=H,			107			CW operating current-2
24	VDD current	CLKIF=L(LVDS)		-	107	_	mA	EN=0, CKDIV[1:0]=10
24	VDD current	SPIEN=L,	IDDCW2		113		mA	Current mode 0 (CC='0') 8-channel active
		CLKIF=H(CMOS)		_	113	-	ma	-
		SPIEN=L,			115	_	mA	Bipolar 3-level Continuous f=5MHz
		CLKIF=L(LVDS)		-	115	_	ША	$V_{PP1}/V_{NN1}=\pm60V$
25	Vss current		Isscw ₂	-	21	-	mA	$VPP1/VNN1=\pm 50$ V $VPP2/VNN2=\pm 5V$
26	VPP1 current		IPP1CW2	_	0.24	_	mA	
27	VPP2 current		IPP2CW2	_	175	_	mA	
28	V _{NN1} current		INN1CW2	-	0.24	_	mA	
29	V _{NN2} current		INN2CW2	_	185	-	mA	

2. Static characteristics

Table 7 Static Characteristics

VLL=2.5V, VDD/VSS=±5V, TA=25°C, VFP[2:0]=VFN[2:0]=000, DRVPADJ=DRVNADJ=0, unless otherwise specified.

No.	lterre	Current el		Spec		Units	Condition
INO.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	HV _{OUT} x output voltage range	ΗV _{OUT} x	-100	-	+100	V	
			Ι	2.0	-	А	P1 active, V _{PP1} /V _{NN1} =±60V
2	HVoutx high-side peak current	Іон	Ι	2.0	I	А	P2 active, Vpp2/Vnn2=±60V, CC=1
			Ι	1.0	I	А	P2 active, V _{PP2} /V _{NN2} =±60V, CC=0
3	HV _{OUT} x high-side GND clamp peak current	IOHCL	Ι	1.0	-	А	Nd active, V _{PP1} /V _{NN1} =V _{PP2} /V _{NN2} =±60V
			_	2.0	_	А	N1 active, Vpp/Vnn=±60V
4	HV _{OUT} x low-side peak current	lol	_	2.0	-	А	N2 active, V _{PP} /V _{NN} =±60V, CC=1
			Ι	1.0	Ι	А	N2 active, V _{PP} /V _{NN} =±60V, CC=0
5	HVoutx low-side GND clamp peak current	IOLCL	Ι	1.0	I	А	Pd active, Vpp1/Vnn1=Vpp2/Vnn2=±60V
				15		Ω	Iон=100mA, P1 active
6	HVoutx high-side on-resistance	RONH		15		Ω	Іон=100mA, P2 active, CC=1
				23	Ι	Ω	I _{OH} =100mA, P2 active, CC=0
7	HVoutx high-side GND clamp on-resistance	RONHCL	Ι	20	Ι	Ω	Іонсь=100mA, Pd active
				15	1	Ω	IoL=100mA, N1 active
8	HVoutx low-side on-resistance	Ronl	-	15	I	Ω	IoL=100mA, N2 active, CC=1
			-	23	-	Ω	IoL=100mA, N2 active, CC=0
9	HV _{OUT} x low-side GND clamp on- resistance	RONLCL	_	20	_	Ω	I _{OLCL} =100mA, Nd active
10	HV _{OUT} x off-capacitance	CHVOFF	-	34	I	pF	TX _{OUT} x=GND, TRSW=off

3. Dynamic characteristics

Table 8 Dynamic Characteristics

 $V_{LL}=2.5V, V_{DD}/V_{SS}=\pm 5V, T_{A}=25^{\circ}C, CLKP/CLKN=100MHz, VFPCTL[2:0]=VFNCTL[2:0]='000', HV_{OUT} \ load=220 pF//200 \Omega, LV_{OUT} \ load=47 pF//200 \Omega, unless otherwise specified.$

Na	Itomo	Symbol		Spec		Linita	Condition
No.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	Output frequency	fout	-	20	-	MHz	
2	Output rise propagation delay	t _{dr}	-	40	_	ns	
3	Output fall propagation delay	t _{df}	_	40	_	ns	
4	Output rise propagation delay clamp	t _{drCL}	-	40	_	ns	
5	Output fall propagation delay clamp	t_{dfCL}	-	40	_	ns	
6	Propagation delay matching	∆t _d	_	±1	±3	ns	
		tr	_	18	_	ns	P1 active
7	Output rise time		_	18	_	ns	P2 active, CC=1
			-	33	-	ns	P2 active, CC=0
		t _{rCL}	-	15	-	ns	Pd active
		t _f	_	18	_	ns	N1 active
8	Output fall time		-	18	_	ns	N2 active, CC=1
0			_	33	_	ns	N2 active, CC=0
		t _{fCL}	_	15	_	ns	Nd active
9	2nd harmonic distortion	HD2	_	-40	_	dBc	
10	Pulse cancellation	HDPC	_	-40	_	dBc	Bipolar, 2-cycle, f _{OUT} =5MHz
10	Puise cancellation	HDPC2	-	-40	_	dBc	
11	RMS output jitter	tJ	_	10	_	ps	Bipolar CW, f _{OUT} =5MHz, V _{PP} /V _{NN} =±5V, HV _{OUT} load=50Ω
12	Crosstalk between channels	X _{TLK}	-	-70	-	dB	f _{oυτ} =5MHz, 10V _{p-p} , HV _{oυτ} load=50Ω

OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER S-UM5588 Rev.1.0_00

4. Integrated peripheral circuits characteristics

4.1 T/R Switch characteristics

Table 9 T/R Switch Characteristics

V_{LL}=2.5V, V_{DD}/V_{SS}=±5V, V_{PP}1/V_{NN}1=V_{PP}2/V_{NN}2=±60V, T_A=25°C, unless otherwise specified.

No.	Items	Symbol		Spec		Units	Condition
INO.	items	Symbol	Min.	Тур.	Max.	Units	Condition
1	LV _{OUT} x output voltage range	LV _{OUT} x	-0.85	Ι	+0.85	V	
2	TRSW on-resistance	Rontr	-	15	-	Ω	HVoutx=100mV, LVoutx=0V
3	TRSW on-capacitance	CONTR	I	15	1	pF	LV _{OUT} x=0V
4	TRSW off-resistance on HVOUTx	ROFFTRHV	1	-	-	MΩ	
5	TRSW off-resistance on LVOUTx	ROFFTRLV	8	10	12	kΩ	
6	Spike voltage on HVoutx and LVoutx	V _{TRN}	Ι	Ι	110	mV_{PP}	220pF//200Ω load on HV _{OUT} x 47pF//200Ω load on LV _{OUT} x
7	TRSW turn-on time	t _{dTRON}	Ι	300	Ι	ns	Logic input-to-ready for Rx signal See Fig.15
8	TRSW turn-off time	t _{dTROFF}	_	50	100	ns	See Fig.15

4.2 Analog Switch

Table 10 Analog Switch Characteristics

V_{LL}=2.5V, V_{DD}/V_{SS}=±5V, T_A=25°C, unless otherwise specified.

	No.	Items	Symbol		Spec		Units	Condition
				Min.	Тур.	Max.		Condition
	1	ASW on-resistance	Ronasw	-	250	-	Ω	

4.3 HV Blocking Diode

Table 11 HV Blocking Diode Characteristics

V_{LL}=2.5V, V_{DD}/V_{SS}=±5V, T_A=25°C, unless otherwise specified.

No.	ltems	Svmbol		Spec		Units	Condition	
INO.	Items	Symbol	Min.	Тур.	Max.	Units	Condition	
1	Forward valtage	V	_	1.0		V	I⊧=100mA	
'	Forward voltage	V_{FHVD}	_	1.2	_	V	I⊧=200mA	
2	Reverse voltage	VRHVD	200	_	-	V	I _R =1µA	

4.4 LV Noise-cut Diode

Table 12 LV Noise-cut Diode Characteristics

V_{LL}=2.5V, V_{DD}/V_{SS}=±5V, T_A=25°C, unless otherwise specified.

No.	Itomo	Sumbol		Spec		Units	Condition
INO.	Items	Symbol	Min.	Тур.	Max.	Units	Condition
1	Forward voltage	Venie	-	1.1	-	V	I⊧=100mA
	Forward voltage	V _{FLVD}	-	1.25	-	V	I⊧=200mA

4.5 Thermal Protection

THP reset hysteresis

Table 13 Thermal Protection Characteristics

THYSTHP

	V _{LL} =2	2.5V, V _{DD} /V _{SS} =±5V, T _A =25°C, unless	s otherwise	specif	fied.				
	No	Itomo	Symbol		Spec		Linita	Condition	
	No.	lo. Items	Symbol	Min.	Тур.	Max.	Units		
				90	110	120	°C	THPCTL[1:0]=00	
	1	TUD tomporature threshold	T	120	130	140	°C	THPCTL[1:0]=01	
		THP temperature threshold	Ттнр	140	150	160	°C	THPCTL[1:0]=10	
				I	Disabled	_	°C	THPCTL[1:0]=11 (THP is	

5

10

20

°C

is disabled)

2

Operation Mode

Section	EN	CSP	SPIEN*2	TRIG	Tx Pattern Signal	SPI LVDS Receiver	Memory Write	Memory Read	Register Write	Register Read	Тх	Rx	Operation mode	
А	1	0	0	×	×	Bias on	-	-	-	_	-	-	IC disabled	
			1			Bias off								
			0			Bias on	\checkmark	\checkmark	-	\checkmark			IC disabled,	
В	1	1	1	×	×	Bias off	-	_	_	_	-		W/R of Memory and Read of Register	
			0			Bias on	\checkmark	\checkmark	\checkmark	\checkmark			Rx, W/R of Memory or	
С	0	1	1	×	×	Bias off	-	_	_	_	-		Register, Reset of Tx Operation	
	0	0	0			Bias on						√*1	Rx & Reset of Tx	
D	0	0	1	1	×	Bias off	-	_	-	-	-	v '	Operation	
-	0	0	0		0	Bias on					√*1		Τ	
E	0	0	1	0	Generated	Bias off	-	-	_	-	✓ '	-	Тх	
F	0	0	0	0	2020	Bias on						√*1	Dv	
F	0 0 1	0		none	Bias off		-	_	_	-	v '	Rx		

Table 14 Operation Mode

*1. Individual register parameter on Tx/Rx active channel (TXACT[x] and RXACT[x]) is necessary to be set "1".

*2. SPIEN Signal is used to reduce the bias current of SPI LVDS Receiver when SPI is not used. (Power on/off time of LVDS receiver is <300ns/<100ns.)

Remark <a>: Available

-: Not available

×: Don't care

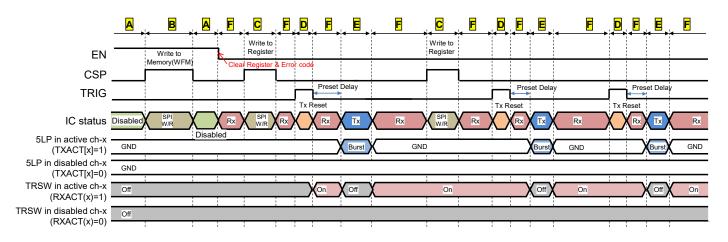


Figure 9 An Example of Operating Sequence

■ SPI Header Configuration

	SDATA Control Header (First 1Byte of SDATA)											
D7 (MSB)	D6	D5	D4	D3	D2	D1	D0 (LSB)	SPI Operation				
0	0	0	0					Write to the first 7Byte (R#0 to R#6) Control Registers and CRC[7:0]				
0	1	0	0					Write to all 16Byte Control Registers and CRC[7:0]				
1	0	0	0					N/A				
1	1	0	0					Write to Memory and CRC[7:0]				
0	0	0	1			0000 eserved	ł)	Read from the first 7Byte (R#0 to R#6) Control Registers and CRC[7:0]				
0	1	0	1		(***		- /	Read from all 16Byte Control Registers and CRC[7:0]				
1	0	0	1					N/A				
1	1	0	1					Read from Memory and CRC[7:0] through SDOUT pin				
×	×	1	0					Read from ERROR[7:0] through SDOUT pin				
×	×	1	1					Read from DSUM[7:0] through SDOUT pin				

Table 15 SPI Operation Table

< 8bit CRC Conditions>

CRC initial value = 00000000 CRC Polynomial equation is $X^{8}+X^{5}+X^{4}+1$

Remark ×: Don't care

■ Access to Memory or Registers with SPI

1. SPI write to memory or registers operation

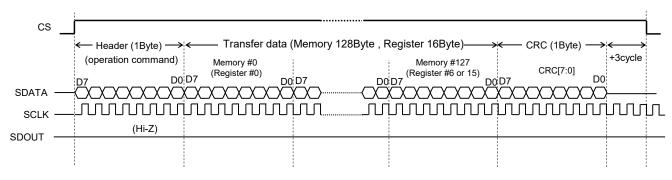


Figure 10 Sequence of Writing to Memory or Registers with SPI

Remark <CRC Conditions>

CRC initial value = 00000000 CRC Polynomial equation is $X^{8}+X^{5}+X^{4}+1$

In SPI "WRITE" operation, internal logic circuit also calculates the CRC ,and writes it to internal Register DSUM[7:0]. If CRC[7:0] matches DSUM[7:0], ERROR[0] = 0. If unmatched, ERROR[0] = 1 and FAULT pin reports, unless fault report is released.

2. Read back form memory or registers operation

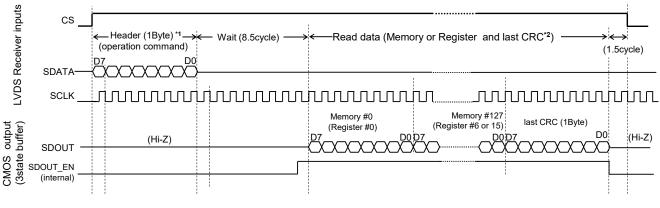
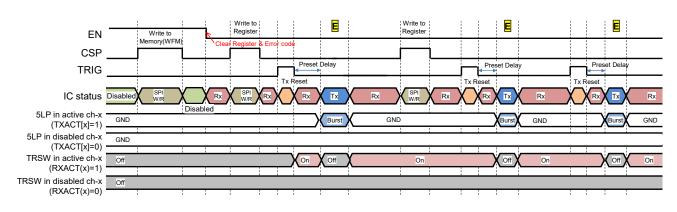


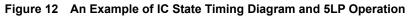
Figure 11 Sequence of Reading from Memory or Registers with SPI

*1. In case of "READ" operation, SDATA inputs except for Header are ignored. (CRC error detection is disabled).

*2. Last CRC is the received CRC data from FPGA in previous "WRITE" operation to Memory or Register.



■ 5LP+TRSW Operation Example



E Tx starts from TRIG fall edge with preset delay time. TRSW turns on except for Tx Burst period or IC-disabled.

Generating Tx WF Pattern

	IVI#	nem	DI			04				DU
	0	Pulse #0	CODE0	[1]	[0]	W0 [4]	(31	121	(11)	W0 [0]
	1	Pulso #1	CODE1		CODE1	W1	W1	W1	W1	W1
STODIE:01			CODE2		CODE2		[3] W2	[2] W2	[1] W2	[0] W2
310F[0.0]	2	Pulse #2	[2]	[1]	[0]	[4]	[3]	[2]	[1]	[0]
•	:		:	:	:	:	1 :			
			CODE127	CODE127	CODE127	W127	W127	W127	W127	W127
	12/	Pulse #127	[2]	[1]	[0]	[4]	[3]	[2]	[1]	[0]
Register	R#	DT	D6	D5	D	4	D3	D2	D1	D0
•	0	reserved	START[6]					START[2]	START[1]	START[0]
	1									STOP[0]
	2									THPCTL[0] REPEAT[0]
	4									VFN[0]
	5	TXACT[7]	TXACT[6]					TXACT[2]	TXACT[1]	TXACT[0]
ELAY	6	RXACT[7]						RXACT[2]	RXACT[1]	RXACT[0]
_	7									BASEDL[0]
	-									CHODL[0]
										CH1DL[0] CH2DL[0]
-										CH3DL[0]
	12	CH4DL[7]	CH4DL[6]					CH4DL[2]	CH4DL[1]	CH4DL[0]
	13	CH5DL[7]	CH5DL[6]					CH5DL[2]	CH5DL[1]	CH5DL[0]
	14									CH6DL[0]
	15	CH/DL[7]	I CH7DL[6]	I I CH7DL	151 I CH70	DLI4I I C	H/DL[3]	CH/DL[2]	CH/DL[1]	CH7DL[0]
	START[6:0]→	START[6:0]→ 1 STOP[6:0]→ 2	0 Pulse #0 1 Pulse #1 STOP[6:0]> 2 Pulse #1 STOP[6:0]> 2 Pulse #2 	0 Pulse #0 CODE0 [2] 1 Pulse #1 CODE1 [2] STOP[6:0] ⇒ 2 Pulse #2 [2] • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • • <	0 Pulse #0 CODE0 (2) CODE1 (2) 1 Pulse #1 CODE1 (2) CODE1 (2) 1 Pulse #1 CODE1 (2) CODE1 (2) STOP[6:0] 2 Pulse #2 CODE2 CODE2 2 Pulse #2 CODE1 (2) 11 11 2 Pulse #127 CODE2 CODE127 CODE127 127 Pulse #127 CODE127 CODE127 CODE127 0 reserved STARTIG START STOP[6] START 2 NV MUL-RPT reserved STARTIG START 3 REPEATI71 REPEATI71 REPEATI71 REPEATI6] BASED 4 DRVPADJ VFP[2] VFP[4] VFP[4] 5 TARCT[17] BASEDL[7] CHOB BASEDL[7] 4 DRVPADJ VFP[2] VFP[4] VFP[4] 5 TARCT[17] BASEDL[7] BASEDL[7] BASEDL[6] BASED 9 CHIDL[7] CHODL[6	0 Pulse #0 CODE0 CODE0 CODE0 CODE0 CODE0 CODE0 CODE1 CODE1 <th< td=""><td>0 Pulse #0 CODE0 CODE0 CODE0 W0 1 Pulse #1 CDI 101 101 101 101 1 Pulse #1 CDI 101 101 101 101 STOP[6:0] ⇒ 2 Pulse #2 CDIE CODE2 CODE2 W2 2 Pulse #2 CI 11 101 141 1 0 1 1 101 141 1 0 1 1 101 141 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 reserved START[6] START[7] START[7] START[7] START[7] START[7] START[7]</td><td>0 Pulse #0 CODE0 CODE0 CODE0 W0 W0 W0 W1 W1</td><td>0 Pulse #0 CODE0 CODE0 CODE0 W0 W1 W1</td><td>0 Pulse #0 CODE0 CODE0 CODE0 W0 W0 W0 1 Pulse #1 CODE1 CODE1 CODE1 CODE1 W1 W1</td></th<>	0 Pulse #0 CODE0 CODE0 CODE0 W0 1 Pulse #1 CDI 101 101 101 101 1 Pulse #1 CDI 101 101 101 101 STOP[6:0] ⇒ 2 Pulse #2 CDIE CODE2 CODE2 W2 2 Pulse #2 CI 11 101 141 1 0 1 1 101 141 1 0 1 1 101 141 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 1 1 101 141 101 141 1 1 reserved START[6] START[7] START[7] START[7] START[7] START[7] START[7]	0 Pulse #0 CODE0 CODE0 CODE0 W0 W0 W0 W1 W1	0 Pulse #0 CODE0 CODE0 CODE0 W0 W1 W1	0 Pulse #0 CODE0 CODE0 CODE0 W0 W0 W0 1 Pulse #1 CODE1 CODE1 CODE1 CODE1 W1 W1

WFM M# Item D7

De

Delay time resolution = 5ns

Truth Table

Table 16 Truth Table

	IC status	S	Exte	ernal	singal	Internal	Control	Register		NFM DE[2	:0]	Control Register		M	OSFE ⁻	CHx T/ASW	5LP //TRS\	N stat	us			Output ate
	mode	SPI	EN	cs	TRIG	Tx-PT(x)	ТХАСТ	RXACT	[2]	[1]	[0]	INV	P1	N1	P2	N2	Pd	Nd	250Ω ASW	TRSW	TXOUT _×	LVOUTx
A	IC disabled	no op.	1	0	×	none	×	×	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
В		Mem. W	1	1	×	none	×	×	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
		Memory	0	1	×	none	0	0	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
	Rx & Tx Reset	W/R	0	1	×	none	0	1	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	ON	GND	HVOUT _x
С	by SPI W/R	or Pogiator	0	1	×	none	1	0	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
	-	Register W/R	0	1	×	none	1	1	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	ON	GND	HVOUT _x
			0	0	1	none	0	0	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
	Rx & Tx Reset		0	0	1	none	0	1	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	ON	GND	HVOUT _x
Ρ	By TRIG	no op.	0	0	1	none	1	0	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
			0	0	1	none	1	1	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	ON	GND	HVOUT _x
			0	0	0	Gen.	1	×	0	0	0	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
			0	0	0	Gen.	1	×	0	0	1	0	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	+HV1	10kΩ
			0	0	0	Gen.	1	×	0	0	1	1	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	-HV1	10kΩ
			0	0	0	Gen.	1	×	0	1	0	0	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	-HV1	10kΩ
			0	0	0	Gen.	1	×	0	1	0	1	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	+HV1	10kΩ
F	Тх	no op.	0	0	0	Gen.	1	×	0	1	1	×				N	/A	-			N	/A
	17	no op.	0	0	0	Gen.	1	×	1	0	0	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
			0	0	0	Gen.	1	×	1	0	1	0	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	+HV2	10kΩ
			0	0	0	Gen.	1	×	1	0	1	1	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	-HV2	10kΩ
			0	0	0	Gen.	1	×	1	1	0	0	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	-HV2	10kΩ
			0	0	0	Gen.	1	×	1	1	0	1	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	+HV2	10kΩ
			0	0	0	Gen.	1	×	1	1	1	×		1		N			1		N	
F	Rx	no op.	0	0	0	none	×	0	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	GND	10kΩ
Ľ	1.0	no op.	0	0	0	none	×	1	×	×	×	×	OFF	OFF	OFF	OFF	ON	ON	ON	ON	GND	HVOUT _x

Remark ×: Don't care

DRVP	DRVN	I _{OUT} [A]				
ADJ	ADJ	P1	N1			
0	0	2	2			
0	1	2	2.1			
1	0	2.1	2			
1	1	2.1	2.1			

Table 17 Truth Table

Table 18 Truth Table

Current	СС	Iout[A]				
mode	0	P2	N2			
0	0	1	1			
1	1	2	2			

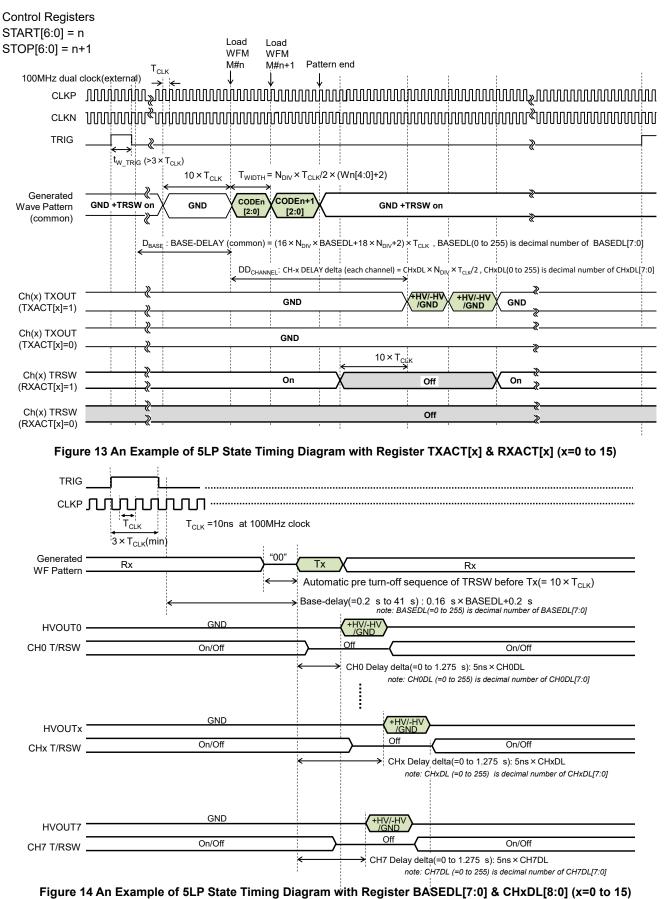
Ň	VFPCTL	-	VPP1-VFP1	VPP2-VFP2
[2]	[1]	[0]	[V]	[V]
0	0	0	5	5
0	0	1	5.15	5.15
0	1	0	5.3	5.3
0	1	1	5.45	5.45
1	0	0	5	5
1	0	1	4.85	4.85
1	1	0	4.7	4.7
1	1	1	4.55	4.55

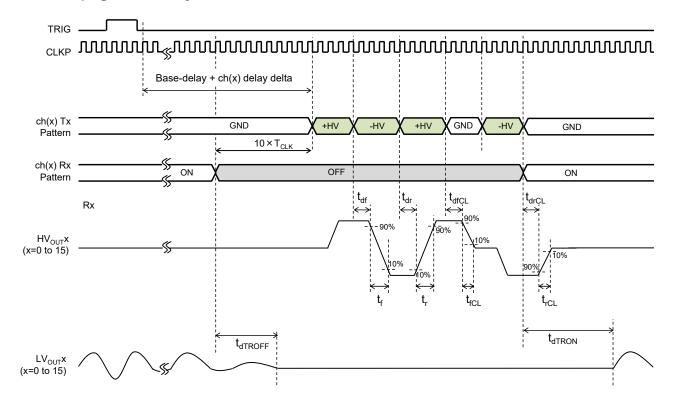
Table 19 Truth Table

\\	/FNCT	L r	VFN1-VNN1	VFN2-VNN2								
[2]	[1]	[0]	[V]	[V]								
0	0	0	5	5								
0	0	1	5.15	5.15								
0	1	0	5.3	5.3								
0	1	1	5.45	5.45								
1	0	0	5	5								
1	0	1	4.85	4.85								
1	1	0	4.7	4.7								
1	1	1	4.55	4.55								

Table 20 Truth Table

Timing Chart





■ Tx Propagation Delay and Rise/Fall Time Definition



■ Tx Pulse Width and Delay Control Table

Cloc	k frequency = 10	00MHz	(T _{CLK} =10ns)					
No.	Items		Symbol		Spec		Units	Note
INO.	items		Symbol	Min.	Тур.	Max.	Units	Note
		N _{DIV} =1		10	-	165		Twidth [ns] = Ndiv $\times T_{CLK}/2 \times (WIDTHx + 2)$
1	Tx pulse width	N _{DIV} =2	Twidth	20	_	330	ns	WIDTHx(=0 to 31) is decimal number of
		N _{DIV} =4		40	-	660		WIDTHx[4:0] in memory #x, x=0 to 127
		N _{DIV} =1		-	5	-		
2	Tx pulse width resolution	N _{DIV} =2	ΔTwidth	_	10	-	ns	ΔTwidth=Ndiv×Tclk/2
		N _{DIV} =4		_	20	-		
		N _{DIV} =1		0.2	-	41		D _{BASE} =(16×N _{DIV} ×BASEDL+18×N _{DIV} +2)×T _{CLK}
3	3 Base delay range	N _{DIV} =2	DBASE	0.38	_	81.98	μs	BASEDL(=0 to 255) is decimal number of
		N _{DIV} =4		0.74	-	163.94	μο	BASEDL[7:0]
		N _{DIV} =1		_	0.16	_		
4	Base delay resolution	N _{DIV} =2	ΔD_{BASE}	_	0.32	-	μs	$\Delta D_{BASE} = 16 \times N_{DIV} \times T_{CLK}$
	10301011011	N _{DIV} =4		_	0.64	I		
	CHx delay	N _{DIV} =1		0	Ι	1275		DD _{CHANNEL} = N _{DIV} ×T _{CLK} /2×CHxDL
5	delta range	N _{DIV} =2	DD _{CHANNEL}	0	Ι	2550	ns	CHxDL(=0 to 255) is decimal number of CHxDL[7:0]
	(x=0 to 15)	N _{DIV} =4		0	Ι	5100		x=0 to 7
	CHx delay	N _{DIV} =1		-	5	-		
6	delta resolution	N _{DIV} =2		_	10	_	ns	ΔDD _{channel} =N _{DIV} ×T _{clk} /2
	resolution	N _{DIV} =4		-	20	_		

Table 21 Tx Pulse Width and Delay Control Table

 $\label{eq:Remark} \begin{array}{ll} \textbf{Remark} & \textbf{N}_{\text{DIV}}(=1,2,4) \text{ is internal clock dividing factor with Register CKDIV[1:0].} \\ & \textbf{CKDIV}[1:0]=00: \ \textbf{N}_{\text{DIV}}=1 \\ & \textbf{CKDIV}[1:0]=01: \ \textbf{N}_{\text{DIV}}=2 \\ & \textbf{CKDIV}[1:0]=10,11: \ \textbf{N}_{\text{DIV}}=4 \end{array}$

OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER S-UM5588 Rev.1.0_00

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Memory MAP

			Tab	le 22 Memo	ry Map				
Memory #	D7	D6	D5	D4	D3	D2	D1	D0	
0		CODE0[2:0]				WIDTH0[4:0]			
1		CODE1[2:0]			WIDTH1[4:0]				
2		CODE2[2:0]			WIDTH2[4:0]				
3	CODE3[2:0]			WIDTH3[4:0]					
:	:			:					
:	:			:					
:	:					:			
124	CODE124[2:0]					WIDTH124[4:()]		
125	CODE125[2:0]					WIDTH125[4:0)]		
126	CODE126[2:0]					WIDTH126[4:0	0]		
127	CODE127[2:0]					WIDTH127[4:0)]		

Remark 1. In Memory Map, each 1-byte code consists of upper 3-bit CODEx[3:0] and lower 5-bit WIDTHx[4:0]. Suffix "x" corresponds to 1-byte Memory number (x=0 to 127).

- 2. CODEx[2:0] stands for an output state of Tx burst as shown in Truth Table.
- 3. WIDTHx[4:0] expresses the pulse width (T_{WIDTH}) which is calculated as follows. T_{WIDTH} [ns] = N_{DIV} ×T_{CLK}/2 × (WIDTHx + 2)
- 4. Where, T_{CLK} is the CLKP/CLKN clock period, WIDTHx(=0 to 31) is decimal number of WIDTHx[4:0] and N_{DIV}(=1,2,4) is internal clock dividing factor with Register CKDIV[1:0].

5. In case of 100MHz CLK,

 $\label{eq:ckdiv} CKDIV[1:0]{=}00 \qquad \qquad : N_{\text{DIV}}{=}1, \, T_{\text{WIDTH}} \, [\text{ns}] \text{ is 10ns to 165ns (5ns step)}.$

- $\label{eq:ckdiv} CKDIV[1:0]=01 \qquad : N_{DIV}=2, \ T_{WIDTH} \ [ns] \ is \ 20ns \ to \ 330ns \ (10ns \ step).$
- $\label{eq:ckdiv} CKDIV[1:0] = 10, \ 11 \qquad : \ N_{\text{DIV}} = 4, \ T_{\text{WIDTH}} \ [ns] \ is \ 40 ns \ to \ 660 ns \ (20 ns \ step).$

Register Parameter Function

	Tabl	e 23 Reg	gister Parameter Function
Items	Register	type	function
WFM Read Address(start)	START [6:0]	common	Starting address of the Waveform Memory for generating the Tx waveform pattern
WFM Read Address(stop)	STOP [6:0]	common	Stop address of the Waveform Memory for generating the Tx waveform pattern
TX Waveform control	INV	common	Inversion control of generating Tx waveform pattern
Wave generation Repeat control(1)	MUL-RPT	common	Multiplying factor selection for REPEAT[7:0] (1: 1×REPEAT[7:0], 0: 16×REPEAT[7:0])
Tx driver current control	СС	common	P2/N2 Tx driver current control (0=1A, 1=2A)
Tx clock dividing	CKDIV [1:0]	common	Internal clock dividing factor "Nɒɪv" selection (00:Nɒɪv=1, 01:Nɒɪv=2, 10 or 11 :Nɒɪv=4)
P1 Driver adjusment	DRVPADJ	common	P1 driver current, 0:2A, 1:2.1A
N1 Driver adjusment	DRVNADJ	common	N1 driver current, 0:2A, 1:2.1A
Built-in power supply control for P1	VFP[2:0]	common	VFP[2]=0: VPP1-VFP1 (=5 to 5.45) : 5+0.15×VFP, VFP is decimal number of VFP[1:0] VFP[2]=1: VPP1-VFP1(=4.55 to 5) : 5-0.15×VFP, VFP is decimal number of VFP[1:0]
Built-in power supply control for N1	VFN[2:0]	common	VFN[2]=0: VFN1-VNN1 (=5 to 5.45) : 5+0.15×VFN, VFN is decimal number of VFN[1:0] VFN[2]=1: VFN1-VNN1(=4.55 to 5) : 5-0.15×VFN, VFN is decimal number of VFN[1:0]
THP detection control	THPCTL[1:0]	common	THP detection control (00:110deg , 01:130deg , 10:150deg, 11:Disabled)
Wave generation Repeat control (2)	REPEAT[7:0]	common	Repeat counts control of Tx waveform pattern generation
Active channel control for Tx	TXACT [7:0]	/channel	Active channel control in Tx, TXACT[x] corresponds to ch(x) in Tx
Active channel control for Rx	RXACT [7:0]	/channel	Active channel control of T/R-SW, RXACT[x] corresponds to TRSW of ch(x)
TX delay control (1)	BASEDL[7:0]	common	Tx offset delay (common to all channel) : (16×Ndiv×BASEDL+14×Ndiv+2)×TcLk BASEDL(=0 to 255) is decimal number of BASEDL[7:0], TcLk is external clock period.
TX delay control (2)	CHxDL [7:0]	/channel	Tx delay for each channel x (x=0 to 7) : N _{DIV} ×T _{CLK} /2×CHxDL CHxDL(=0 to 255) is decimal number of CHxDL[7:0], T _{CLK} is external clock period.

REPEAT[7:0] (Repeat counts control of Tx waveform pattern generation) REPEAT[7:0]=00000000 : repeat count = 1 REPEAT[7:0]=00000001 to 11111110 : repeat count = 1(or 16)×REPEAT[7:0] REPEAT[7:0]=11111111 : continuous

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Register MAP

			Tabl	e 24 Tx Con	trol Register	MAP		
R#	D7	D6	D5	D4	D3	D2	D1	D0
0	reserved	START[6]	START[5]	START[4]	START[3]	START[2]	START[1]	START[0]
1	reserved	STOP[6]	STOP[5]	STOP[4]	STOP[3]	STOP[2]	STOP[1]	STOP[0]
2	INV	MUL-RPT	reserved	СС	CKDIV[1]	CKDIV[0]	THPCTL[1]	THPCTL[0]
3	REPEAT[7]	REPEAT[6]	REPEAT[5]	REPEAT[4]	REPEAT[3]	REPEAT[2]	REPEAT[1]	REPEAT[0]
4	DRVPADJ	VFP[2]	VFP[1]	VFP[0]	DRVNADJ	VFN[2]	VFN[1]	VFN[0]
5	TXACT[7]	TXACT[6]	TXACT[5]	TXACT[4]	TXACT[3]	TXACT[2]	TXACT[1]	TXACT[0]
6	RXACT[7]	RXACT[6]	RXACT[5]	RXACT[4]	RXACT[3]	RXACT[2]	RXACT[1]	RXACT[0]
7	BASEDL[7]	BASEDL[6]	BASEDL[5]	BASEDL[4]	BASEDL[3]	BASEDL[2]	BASEDL[1]	BASEDL[0]
8	CH0DL[7]	CH0DL[6]	CH0DL[5]	CH0DL[4]	CH0DL[3]	CH0DL[2]	CH0DL[1]	CH0DL[0]
9	CH1DL[7]	CH1DL[6]	CH1DL[5]	CH1DL[4]	CH1DL[3]	CH1-DL[2]	CH1DL[1]	CH1DL[0]
10	CH2DL[7]	CH2DL[6]	CH2DL[5]	CH2DL[4]	CH2DL[3]	CH2DL[2]	CH2DL[1]	CH2DL[0]
11	CH3DL[7]	CH3DL[6]	CH3DL[5]	CH3DL[4]	CH3DL[3]	CH3DL[2]	CH3DL[1]	CH3DL[0]
12	CH4DL[7]	CH4DL[6]	CH4DL[5]	CH4DL[4]	CH4DL[3]	CH4DL[2]	CH4DL[1]	CH4DL[0]
13	CH5DL[7]	CH5DL[6]	CH5DL[5]	CH5DL[4]	CH5DL[3]	CH5DL[2]	CH5DL[1]	CH5DL[0]
14	CH6DL[7]	CH6DL[6]	CH6DL[5]	CH6DL[4]	CH6DL[3]	CH6DL[2]	CH6DL[1]	CH6DL[0]
15	CH7DL[7]	CH7DL[6]	CH7DL[5]	CH7DL[4]	CH7DL[3]	CH7DL[2]	CH7DL[1]	CH7DL[0]

■ CRC and ERROR Register

	Та	able 25 CR	C, Calculate	d CRC and	ERROR Re	gister MAP		
Register	D7	D6	D5	D4	D3	D2	D1	D0
CRC	CRC[7:0]							
Calculated CRC	DSUM[7:0]							
Error	ERROR[7:0]							

	Table 26 CRC, Calculated CRC and ERROR Register Function					
CRC[7:0]	Transferred CRC data in SDATA CRC initial value = 00000000					
0110[1:0]	CRC polynomial equation is $X^8 + X^5 + X^4 + 1$					
DSUM[7:0]	Calculated CRC values with transferred SDATA signal					
ERROR[7:0]	 When Error has occurred, ERROR register corresponding to error type is set to be "1". ERROR[7:3] : Not used. ERROR[2]: Threshold over of the junction temperature set in advance. ERROR[1]: Start and stop address for Tx waveform pattern generation are same. ERROR[0]: SPI transfer error (CRC un-match) has occurred. 					

Remark Error[7:0] are cleared when IC is powered on or "EN" becomes form "high" to "low" (fall edge).

Pin Configuration

	-	Table 27 Pin Configuration (1/2)
Pin#	Pin Name	Function
1	LVOUT1	Low voltage output of channel 1
2	LVOUT0	Low voltage output of channel 0
3	HGND	channel 0 to channel 3 Drive power ground (0V)
4	GND	Logic power ground (0V)
5	GND	Logic power ground (0V)
6	EN	Control of chip enable, H=disable, L=enable (50kΩ internal pull-up)
7	FAULT	Fault output flag, open N-MOS drain
8	VDD	Positive low voltage power supply (+5V)
9	CLKP	Positive LVDS/CMOS clock input (up to 100MHz)
10	CLKN	Negative LVDS/CMOS clock Input (up to 100MHz)
11	GND	Logic power ground (0V)
12	TRIG	Tx Trigger signal
13	VLL	Positive low voltage power supply (+2.5 to 3.3V)
14	CLKIF	I/F selection for CLKP/CLKN, H:CMOS L:LVDS (50kΩ internal pull-down)
15	HGND	channel 4 to channel 7 Drive power ground (0V)
16	LVOUT7	Low voltage output of channel 7
17	LVOUT6	Low voltage output of channel 6
18	VFP1	Built-in power supply for channel 4 to channel 7 P-MOS (P1) gate drive
19	HVOUT7	High voltage output of channel 7
20	VPP1	Positive high voltage power supply (0 to +100V) for channel 4 to channel 7 P-MOS (P1) Driver
21	VPP1	Positive high voltage power supply (0 to +100V) for channel 4 to channel 7 P-MOS (P1) Driver
22	HVOUT6	High voltage output of channel 6
23	VPP2	Positive high voltage power supply (0 to +100V) for channel 4 to channel 7 P-MOS (P2) Driver
24	VPP2	Positive high voltage power supply (0 to +100V) for channel 4 to channel 7 P-MOS (P2) Driver
25	VFP2	Built-in power supply for channel 4 to channel 7 P-MOS (P2) gate drive
26	HGND	channel 4 to channel 7 Drive power ground (0V)
27	VFN2	Built-in power supply for channel 4 to channel 7 N-MOS (N2) gate drive
28	VNN2	Negative high voltage power supply (0 to -100V) channel 4 to channel 7 N-MOS (N2) Driver
29	VNN2	Negative high voltage power supply (0 to -100V) channel 4 to channel 7 N-MOS (N2) Driver
30	HVOUT5	High voltage output of channel 5
31	VNN1	Negative high voltage power supply (0 to -100V) channel 4 to channel 7 N-MOS (N1) Driver
32	VNN1	Negative high voltage power supply (0 to -100V) channel 4 to channel 7 N-MOS (N1) Driver
33	HVOUT4	High voltage output of channel 4
34	VFN1	Built-in power supply for channel 4 to channel 7 N-MOS (N1) gate drive
35	LVOUT5	Low voltage output of channel 5
36	LVOUT4	Low voltage output of channel 4
37	HGND	channel 4 to channel 7 Drive power ground (0V)
38 39	SDOUT SPIEN	SPI serial output data (CMOS) Control of SPI Reciver Enable, H=disable, L=enable (50kΩ internal pull-up)
39 40	SDATAP	SPI positive serial input data (LVDS/CMOS)
40	SDATAP	SPI positive serial input data (LVDS/CMOS) SPI negative serial input data (LVDS/CMOS)
41	VDD	Positive low voltage power supply (+5V)
42	GND	Logic power ground (0V)
43	VSS	Negative low voltage power supply (-5V)
44	SCLKP	SPI Positive LVDS/CMOS clock input (up to 100MHz)
46	SCLKN	SPI negative LVDS/CMOS clock Input (up to 100MHz)
47	CSP	SPI positive chip select signal (LVDS/CMOS)
48	CSN	SPI negative chip select signal (LVDS/CMOS)
49	HGND	channel 0 to channel 3 Drive power ground (0V)
50	LVOUT3	Low voltage output of channel 3
51	LVOUT2	Low voltage output of channel 2
V 1		

OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER Rev.1.0_00 S-UM5588

		Table 27 Pin Configuration (2/2)
Pin#	Pin Name	Function
52	VFN1	Built-in power supply for channel 0 to channel 3 N-MOS (N1) gate drive
53	HVOUT3	High voltage output of channel 3
54	VNN1	Negative high voltage power supply (0 to -100V) channel 0 to channel 3 N-MOS (N1) Driver
55	VNN1	Negative high voltage power supply (0 to -100V) channel 0 to channel 3 N-MOS (N1) Driver
56	HVOUT2	High voltage output of channel 2
57	VNN2	Negative high voltage power supply (0 to -100V) channel 0 to channel 3 N-MOS (N2) Driver
58	VNN2	Negative high voltage power supply (0 to -100V) channel 0 to channel 3 N-MOS (N2) Driver
59	VFN2	Built-in power supply for channel 0 to channel 3 N-MOS (N2) gate drive
60	HGND	channel 0 to channel 7 Drive power ground (0V)
61	VFP2	Built-in power supply for channel 0 to channel 3 P-MOS (P2) gate drive
62	VPP2	Positive high voltage power supply (0 to +100V) for channel 0 to channel 3 P-MOS (P2) Driver
63	VPP2	Positive high voltage power supply (0 to +100V) for channel 0 to channel 3 P-MOS (P2) Driver
64	HVOUT1	High voltage output of channel 1
65	VPP1	Positive high voltage power supply (0 to +100V) for channel 0 to channel 3 P-MOS (P1) Driver
66	VPP1	Positive high voltage power supply (0 to +100V) for channel 0 to channel 3 P-MOS (P1) Driver
67	HVOUT0	High voltage output of channel 0
68	VFP1	Built-in power supply for channel 0 to channel 3 P-MOS (P1) gate drive

Table 27 Pin Configuration (2/2)

OCTAL PROGRAMMABLE 5-LEVEL HIGH-VOLTAGE ULTRASOUND TRANSMIT BEAMFORMER S-UM5588 Rev.1.0_00

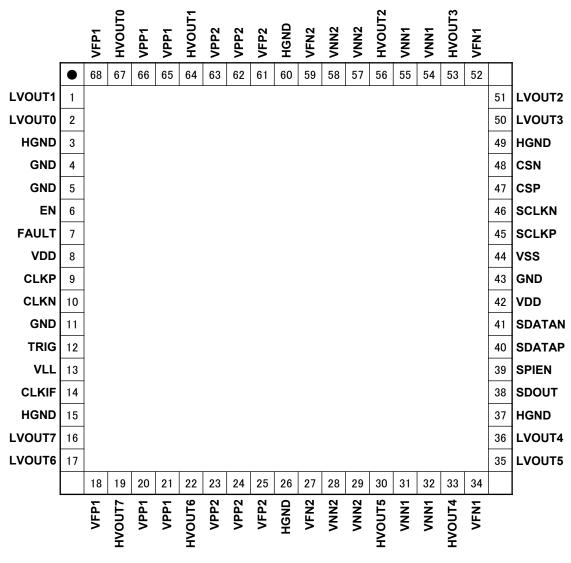


Figure 16 Pin Configuration

Package

_			Table 28 Package	e Drawing Codes		
I	Package Name	Dimension	Tray	Marking	Land	Packing
I	QFN-68(1010)B	QN068-B-P	QN068-B-T	QN068-B-M	QN068-B-L	QN068-B-K

■ Storage, Mounting

1. Storage Conditions

- 1. 1 The storage location should be kept at 5 to 35 °C and 40 to 70% relative humidity. Keeping in a dry box is recommended. Moisture-proof property is assured for 12 months from delivery date for sealed moisture-proof packing, while it is guaranteed for 7 days from unpacked date under the condition above.
- 1. 2 When the storage conditions do not conform to those above or other conditions occur indicating moisture exposure, the ICs should be dried to avoid package cracks. A baking process at 125 °C lasting for 24 hours results in sufficient dehumidification. The baking is not allowed more than twice, and the ICs should be mounted within 7 days after initial baking or within 10 days of total exposure after the second dehumidification.

2. Reflow soldering

The temperature rise may be different in the resin and a terminal part due to the reflow soldering. It is necessary to check the package surface temperature (resin) before setting the temperature profile. **Figure 17** shows the resistance to soldering heat condition for package (Reflow method). Confirm the heat resistance of the package shown below. (Based on JEDEC J-STD-020).

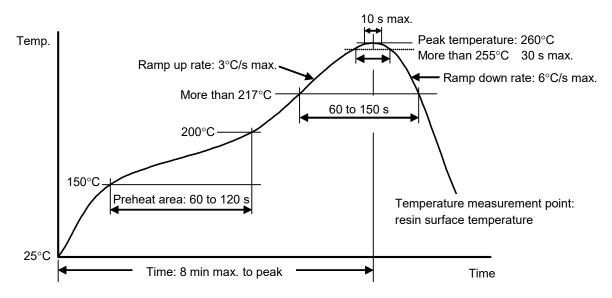


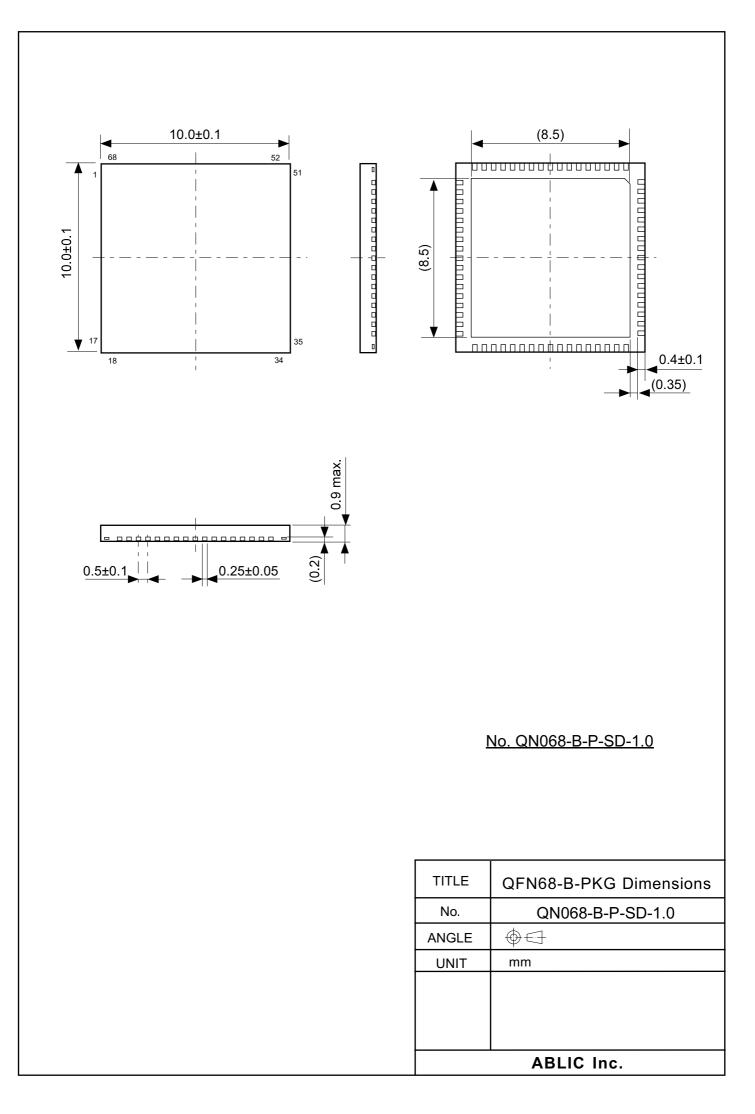
Figure 17 Resistance to soldering heat condition for package (Reflow method)

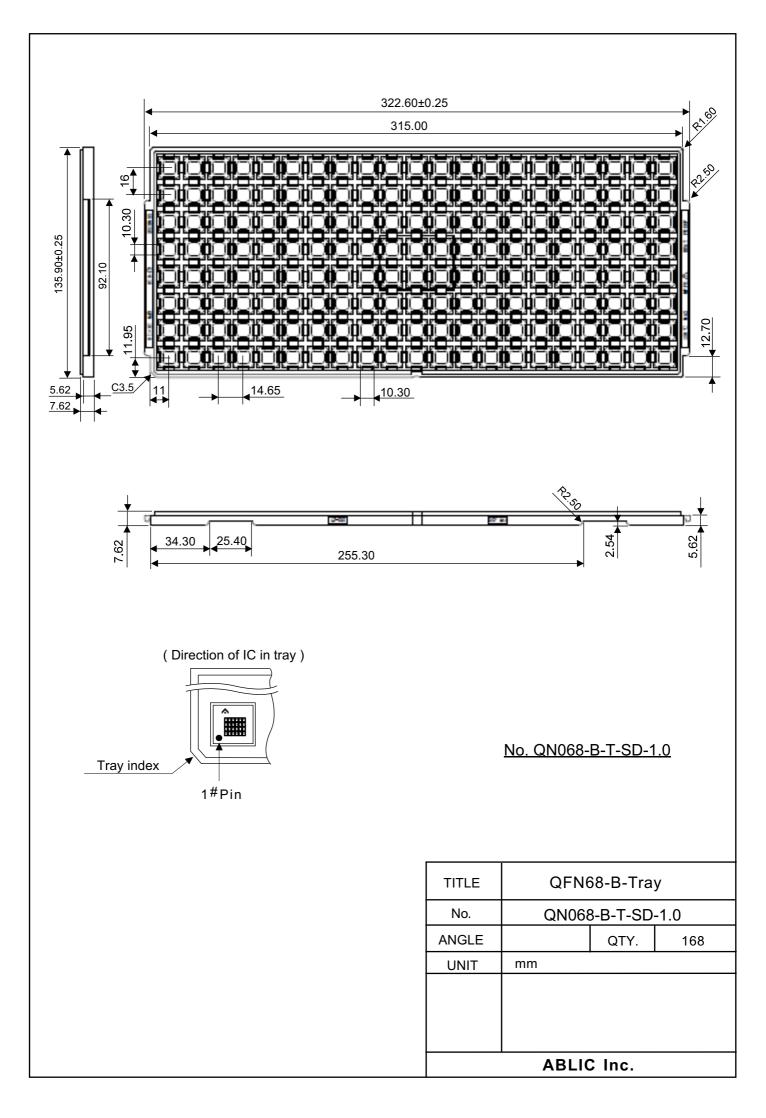
Important Notice

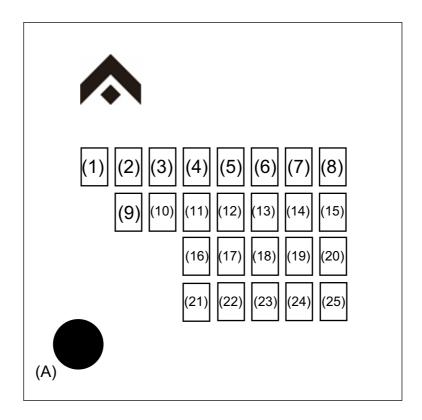
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Cautions

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 - 1.1 Material of container or any device to carry products should be free from ESD, which may be caused by vibration while transportation. It is recommended that electric-conductive container or aluminum sheet be used as an effective countermeasure.
 - 1.2 Those what touch products such as work platform, machine, measurement/test equipment should be grounded.
 - 1.3 Those who deal with products should be grounded through a large series impedance around $100k\Omega$ to $1M\Omega$.
 - 1.4 Prevent friction with other materials made with high polymer.
 - 1.5 Prevent vibration or friction when carrying the printed circuit board (PCB) where products are mounted. To short circuit terminals is a recommended countermeasure to keep the same electric potential on the PCB.
 - 1.6 Avoid dealing with or storing products in an extremely arid environment.
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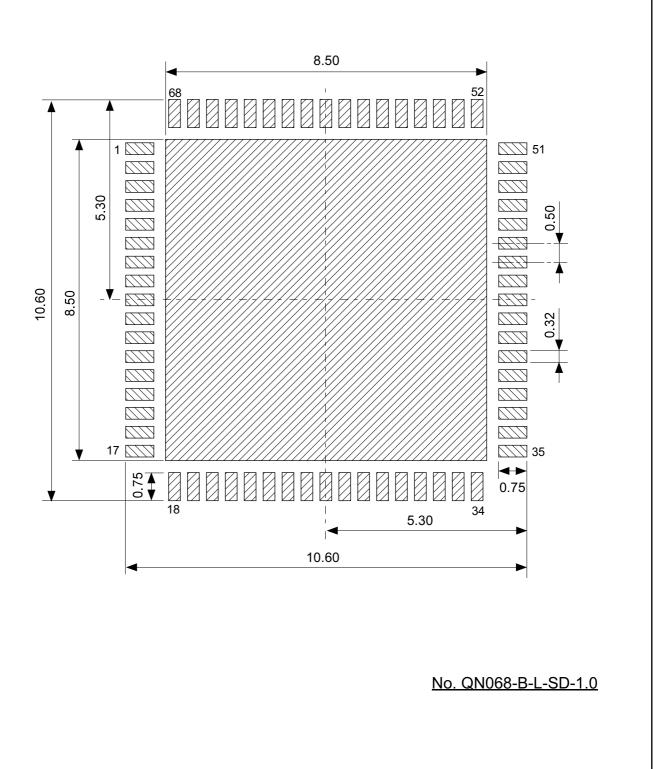




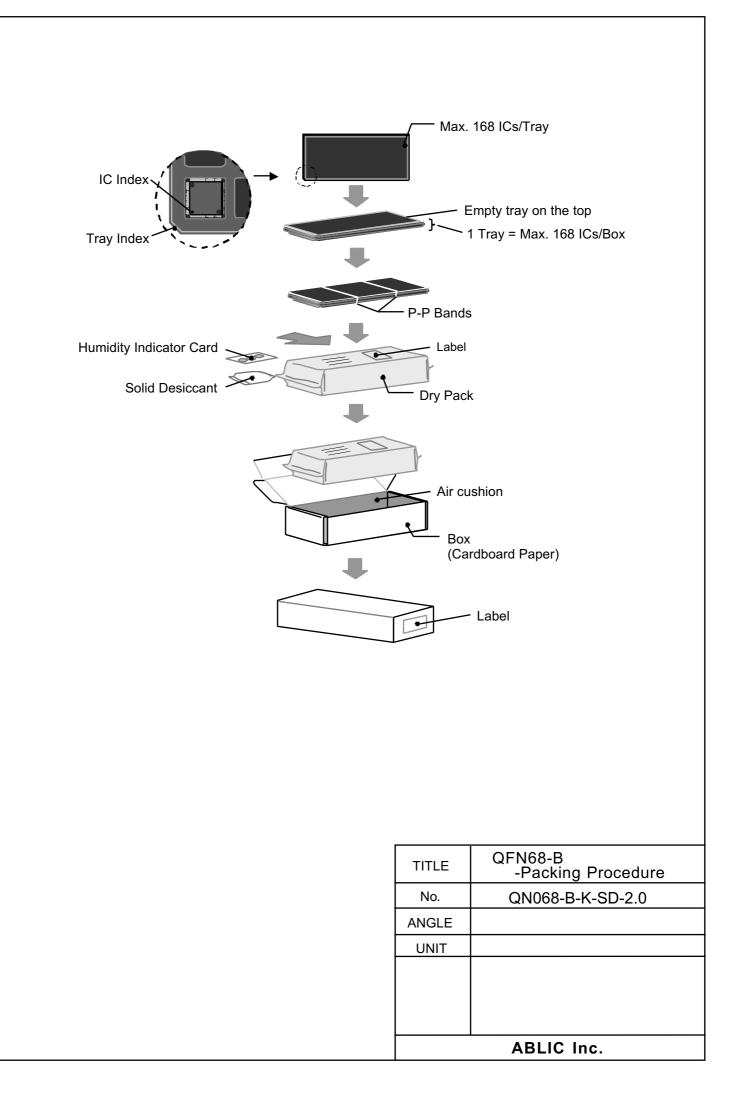
- (1) to (10) : Product code
 (11), (12) : Quality control code
 (13) : Year of assembly
 (14) : Month of assembly
 - (15) : Week of assembly
- (16) to (25) : Quality control code
 - (A) : 1-pin mark

No. QN068-B-M-S1-1.0

TITLE	QFN68-B-Markings			
No.	QN068-B-M-S1-1.0			
ANGLE				
UNIT	TYPE LASER			
ABLIC Inc.				



TITLE	QFN68-B -Land Recommendation					
No.	QN068-B-L-SD-1.0					
ANGLE						
UNIT	mm					
ABLIC Inc.						



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